

Substitute for form 1449A/B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)			Complete if Known	
	Application Number	Not Yet Assigned 10/647462		
	Filing Date	26 AUG 2003		
	First Named Inventor	Joseph E. Geusic		
	Art Unit	2879		
	Examiner Name	Not Yet Assigned Williams		
Sheet	1	of	1	Attorney Docket Number
				M4065.0293/P293-A

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
JW	AA	*6,016,027	01/2000	DeTemple et al.	
JW	AB	*6,031,241	02/2000	Silfvast et al.	
JW	AC	*5,185,552	02/1993	Suzuki et al.	
JW	AD	*5,327,475	07/1994	Golovanivsky et al.	
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FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ⁶
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NON PATENT LITERATURE DOCUMENTS			
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
JW	CA	*W.T. Silfvast, "Intense EUV Incoherent Plasma Sources for EUV Lithography and Other Applications," Journal of Quantum Electronics, Vol. 35, No. 5, May 1999, pp 700-708.	
JW	CB	*J.W. Frame, et al., "Microdischarge Devices Fabricated in Silicon," Appl. Phys. Lett., 71(9), September 1, 1997, pp. 1165-1167.	
JW	CC	*A. El-Habachi et al., "Generation of Intense Excimer Radiation from High-Pressure Hollow Cathode Discharges," Appl. Phys. Lett., Vol. 73, No. 7, August 17, 1998, pp. 885-887.	
JW	CD	*K.H. Schoenbach et al., "Microhollow Cathode Discharges," Appl. Phys. Lett., 68(1), January 1, 1996, pp. 13-15.	
JW	CE	*M.A. Klosner et al., "Intense Xenon Capillary Discharge Extreme-Ultraviolet Source in the 10-16-nm-Wavelength Region," Optics Letters, Vol. 23, No. 20, October 15, 1998, pp. 1609-1611.	

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PRIMARY EXAMINER

5/18/05